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# HMC6146BLC5A

## GaAs MMIC I/Q UPCONVERTER 40 - 44 GHz

### Typical Applications

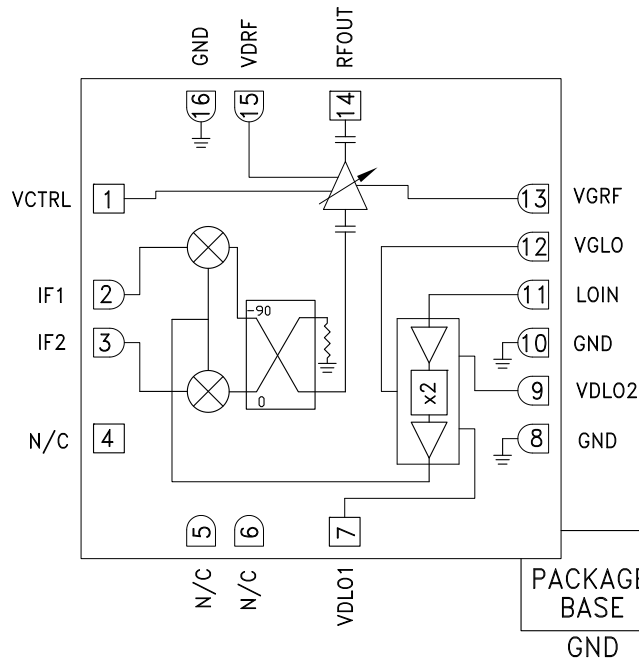
The HMC6146BLC5A is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

### Features

- Conversion Gain: 12 dB
- Sideband Rejection: 25 dBc
- High Output IP3: +27 dBm
- 16 Lead 5x5 mm SMT Ceramic Package: 25 mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC6146BLC5A is a compact GaAs MMIC I/Q variable gain upconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 12 dB with 25 dBc of sideband rejection, and 17 dB of gain control. The HMC6146BLC5A utilizes a RF variable gain amplifier preceded by an I/Q mixer where the LO is driven by a X2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC6146BLC5A is a much smaller alternative to hybrid style single sideband upconverter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

### Electrical Specifications <sup>[1][2]</sup>, $T_A = +25^\circ\text{C}$ , $IF = 2350\text{ MHz}$ , $LO = +4\text{ dBm}$ , $VDLO1, 2 = +3\text{V}$ , $IDLO = 150\text{ mA}$ , $VDRF = +3\text{V}$ , $IDRF = 200\text{ mA}$ , $USB$ <sup>[1][2]</sup>

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF		40 - 42		42 - 44			GHz
Frequency Range, LO		18 - 20		20 - 22			GHz
Frequency Range, IF		0 - 4		0 - 4			GHz
Conversion Gain	9	12		7	10		dB
Sideband Rejection	21	25		14	18		dBc
Dynamic Range		17			13		dB
1 dB Compression (Output)		16			16		dBm
IP3 (Output)		27			28		dBm
2LO / RF Isolation		15			15		dB
Supply Current IDLO <sup>[2]</sup>		150			150		mA
Supply Current IDRF <sup>[2]</sup>		200			200		mA

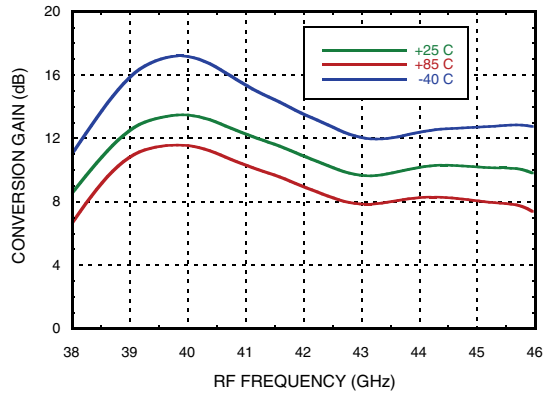
[1] Unless otherwise noted all measurements performed with low side LO, IF = 2350 MHz and external IF 90° hybrid.

[2] Adjust Vgg between -2 to 0V to achieve IDLO = 150 mA and IDRF = 200 mA Typical.

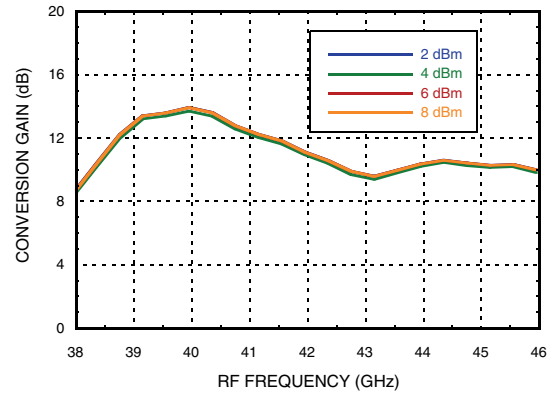


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2350 MHz

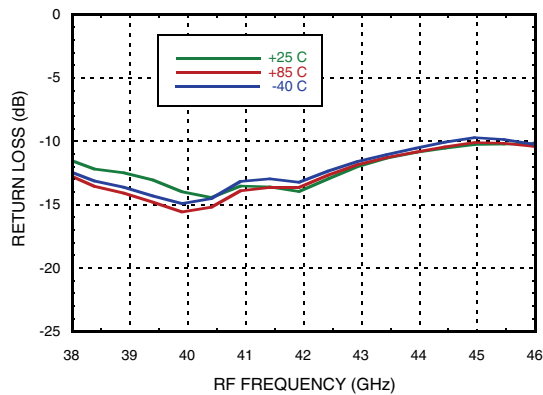
**Conversion Gain, USB vs. Temperature**



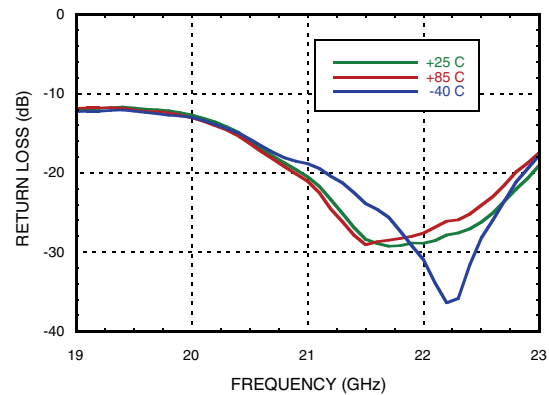
**Conversion Gain, USB vs. LO Drive**



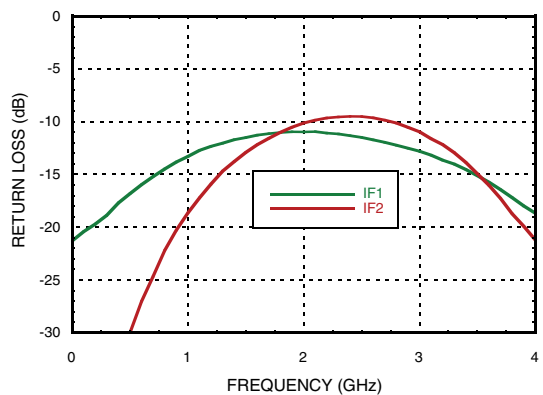
**RF Return Loss vs. Temperature**



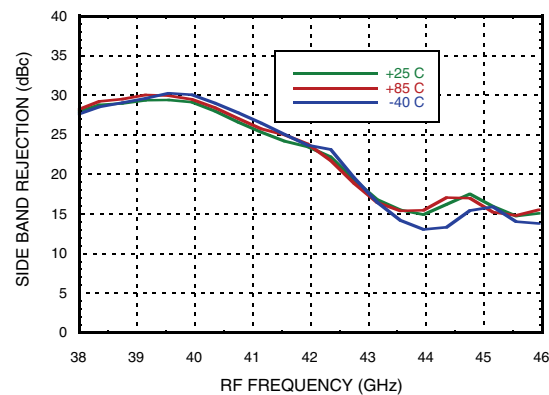
**LO Return Loss vs. Temperature**



**IF Return Loss [1]**



**Sideband Rejection vs. Temperature**



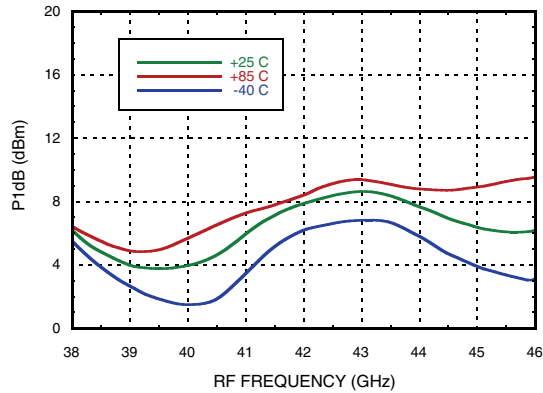
[1] Data taken without external IF 90° hybrid



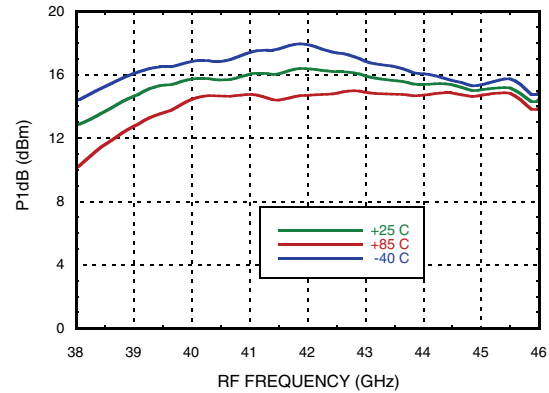
## GaAs MMIC I/Q UPCONVERTER 40 - 44 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2350 MHz

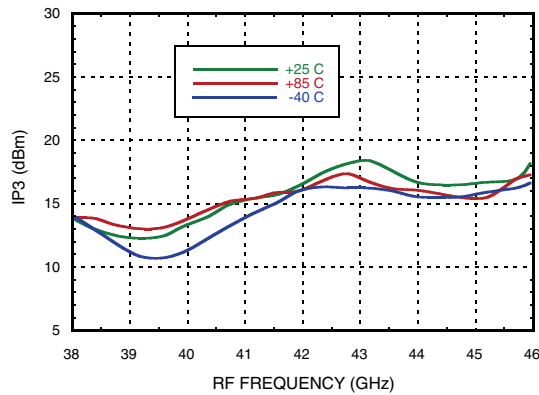
**Input P1dB, USB vs. Temperature**



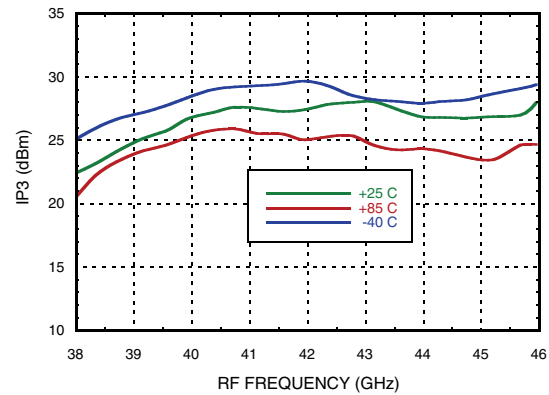
**Output P1dB, USB vs. Temperature**



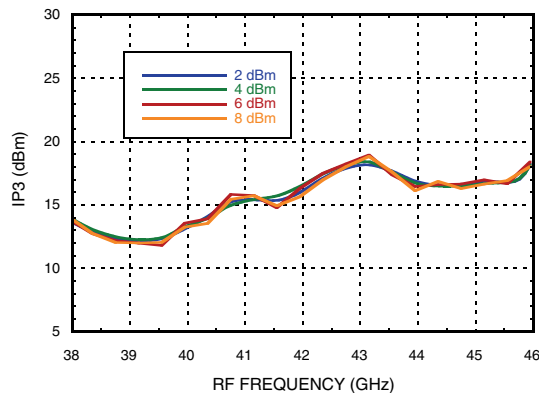
**Input IP3, USB vs. Temperature**



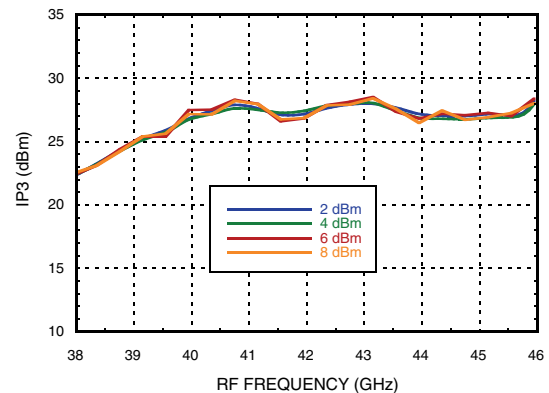
**Output IP3, USB vs. Temperature**



**Input IP3, USB vs. LO Drive**

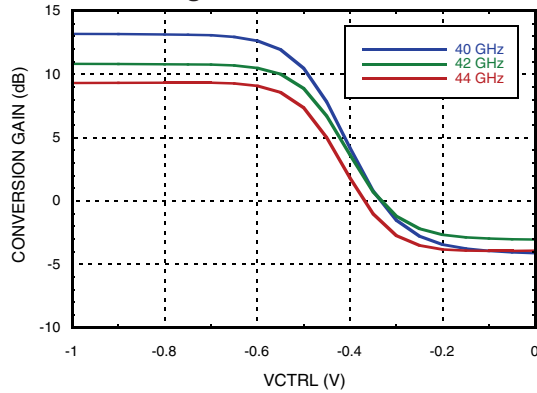


**Output IP3, USB vs. LO Drive**

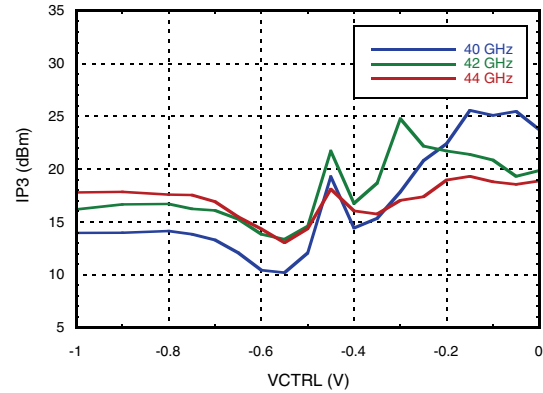


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2350 MHz

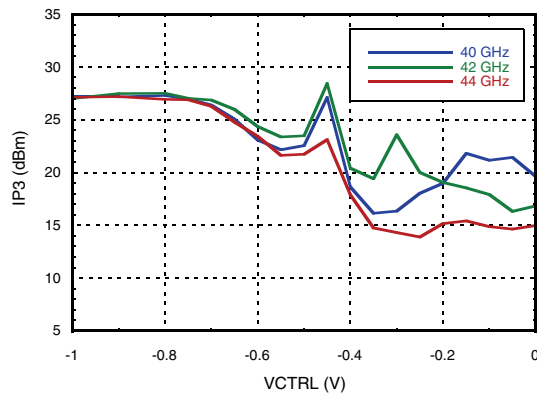
**Conversion Gain, USB vs. Control Voltage [1]**



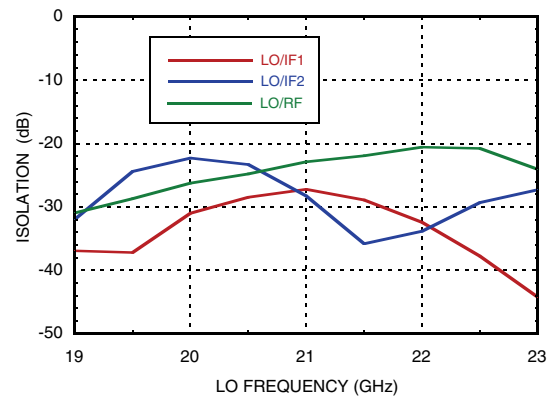
**Input IP3, USB vs. Control Voltage [1]**



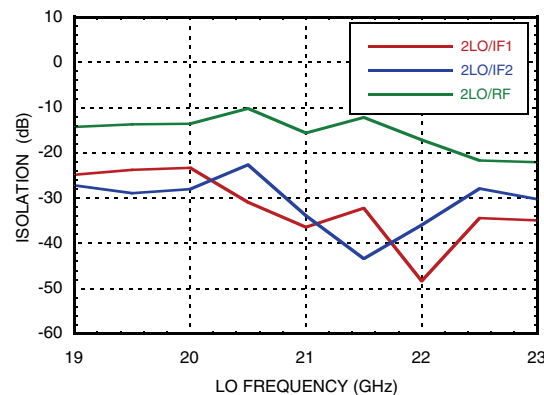
**Output IP3, USB vs. Control Voltage [1]**



**LO Isolation**



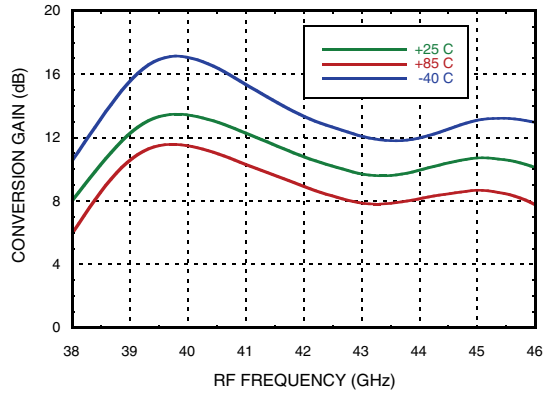
**2LO Isolation**



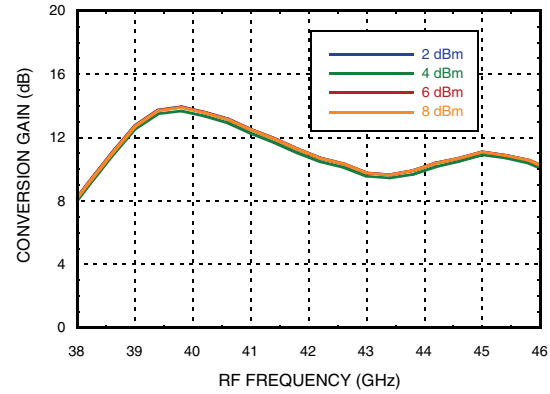
[1] Control voltage plots taken at 150 mA

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3000 MHz

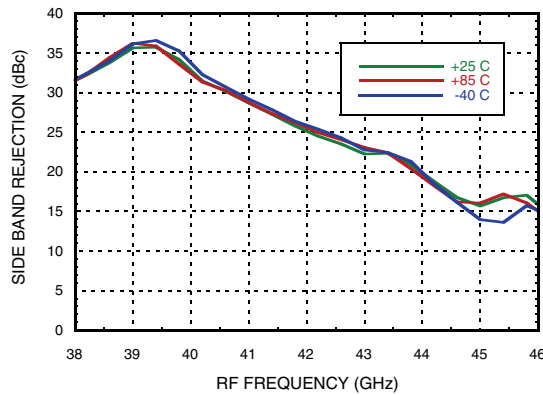
**Conversion Gain, USB vs. Temperature**



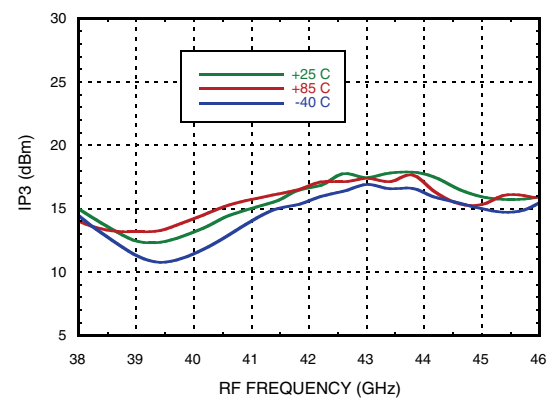
**Conversion Gain, USB vs. LO Drive**



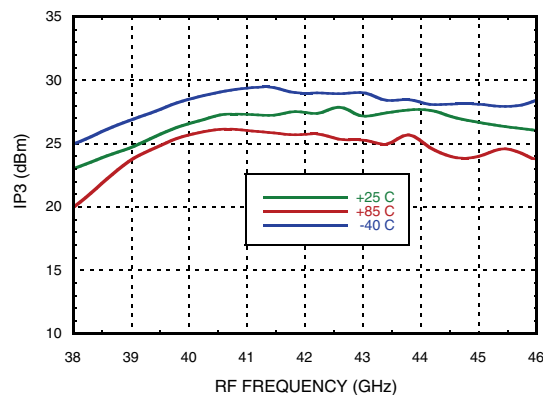
**Sideband Rejection vs. Temperature**



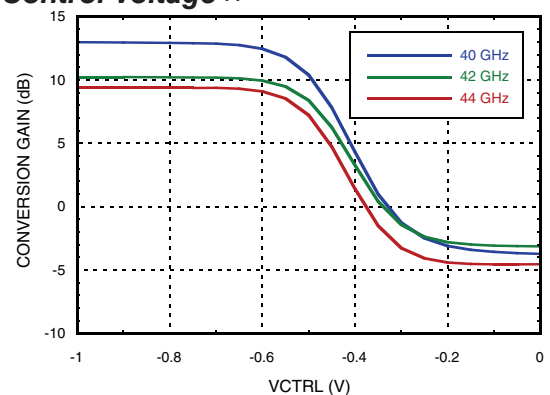
**Input IP3, USB vs. Temperature**



**Output IP3, USB vs. Temperature**



**Conversion Gain, USB vs. Control Voltage [1]**



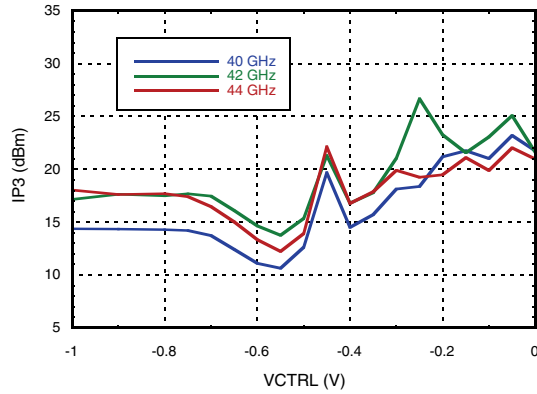
[1] Control voltage plots taken at 150 mA



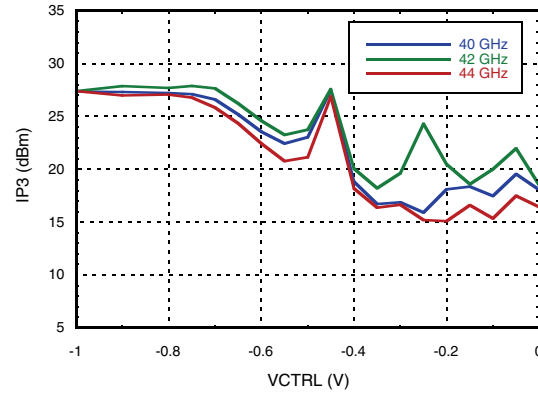
## GaAs MMIC I/Q UPCONVERTER 40 - 44 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3000 MHz

Input IP3, LSB vs. Control Voltage [1]



Output IP3, LSB vs. Control Voltage [1]



[1] Control voltage plots taken at 150 mA

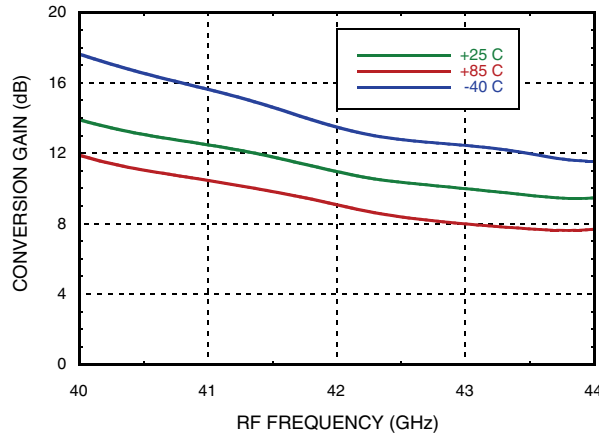




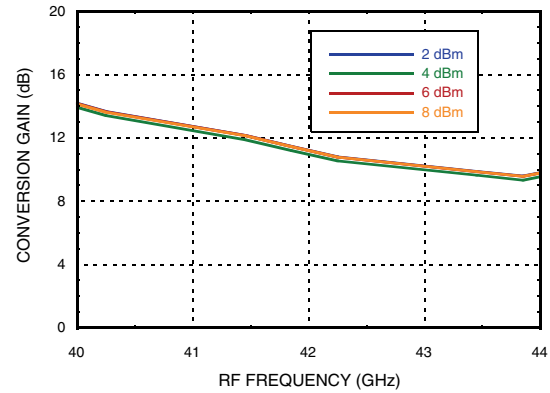
## GaAs MMIC I/Q UPCONVERTER 40 - 44 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3750 MHz

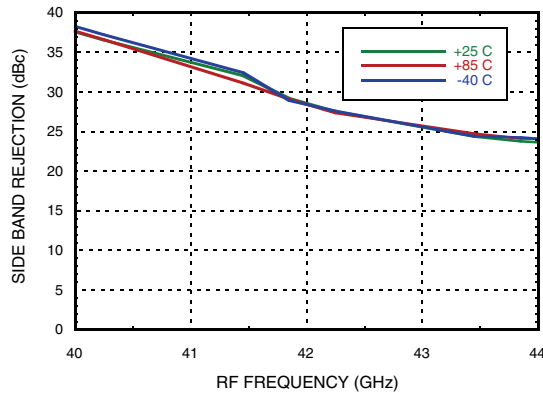
**Conversion Gain, USB vs. Temperature**



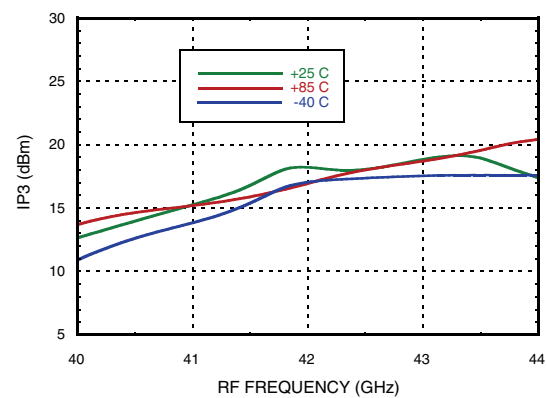
**Conversion Gain, USB vs. LO Drive**



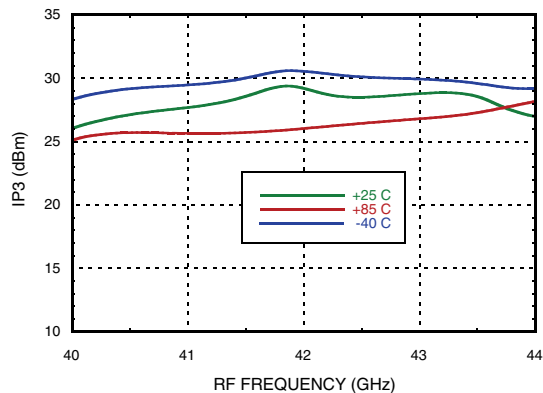
**Sideband Rejection vs. Temperature**



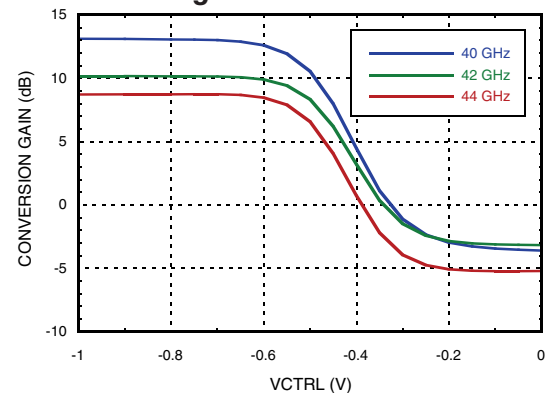
**Input IP3, USB vs. Temperature**



**Output IP3, USB vs. Temperature**



**Conversion Gain, USB vs. Control Voltage [1]**



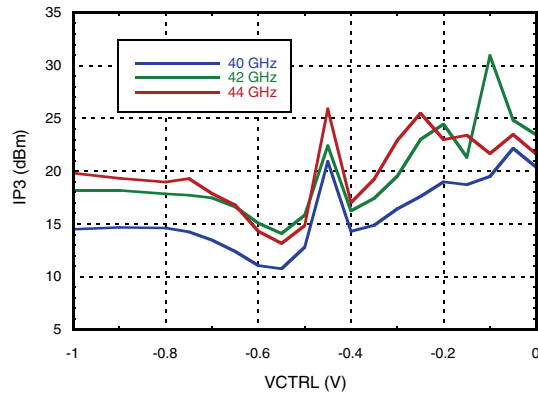
[1] Control voltage plots taken at 150 mA



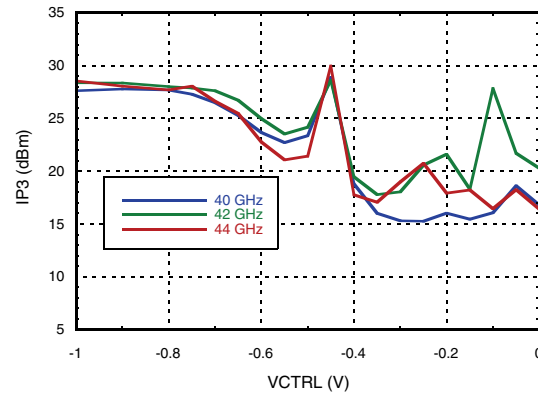
## GaAs MMIC I/Q UPCONVERTER 40 - 44 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3750 MHz

**Input IP3, LSB vs. Control Voltage** [3]



**Output IP3, LSB vs. Control Voltage** [3]



**MxN Spurious Outputs** [1][2]

mIF	nLO				
	0	1	2	3	4
0		31	22		
1	68	76	0		
2	71	88	60		
3	120	110	73		
4	120	120	120		
5	120	120	120		

IF = 2.35 GHz @ -8 dBm  
LO = 19.075 GHz @ +4 dBm

**MxN Spurious Outputs** [1][2]

mIF	nLO				
	0	1	2	3	4
0		28	14		
1	61	63	0		
2	69	85	60		
3	109	109	83		
4	118	118			
5	118	118			

IF = 3 GHz @ -8 dBm  
LO = 19.5 GHz @ +4 dBm

**MxN Spurious Outputs** [1][2]

mIF	nLO				
	0	1	2	3	4
0		25	7		
1	55	67	0		
2	66	91	51		
3	116	108			
4	116	116			
5	116	116			

IF = 4 GHz @ -8 dBm  
LO = 19.75 GHz @ +4 dBm

[1] Data taken without external IF 90° hybrid  
[2] All values in dBc below RF power level (2LO + IF) USB  
[3] Control voltage plots taken at 150 mA



## GaAs MMIC I/Q UP CONVERTER 40 - 44 GHz

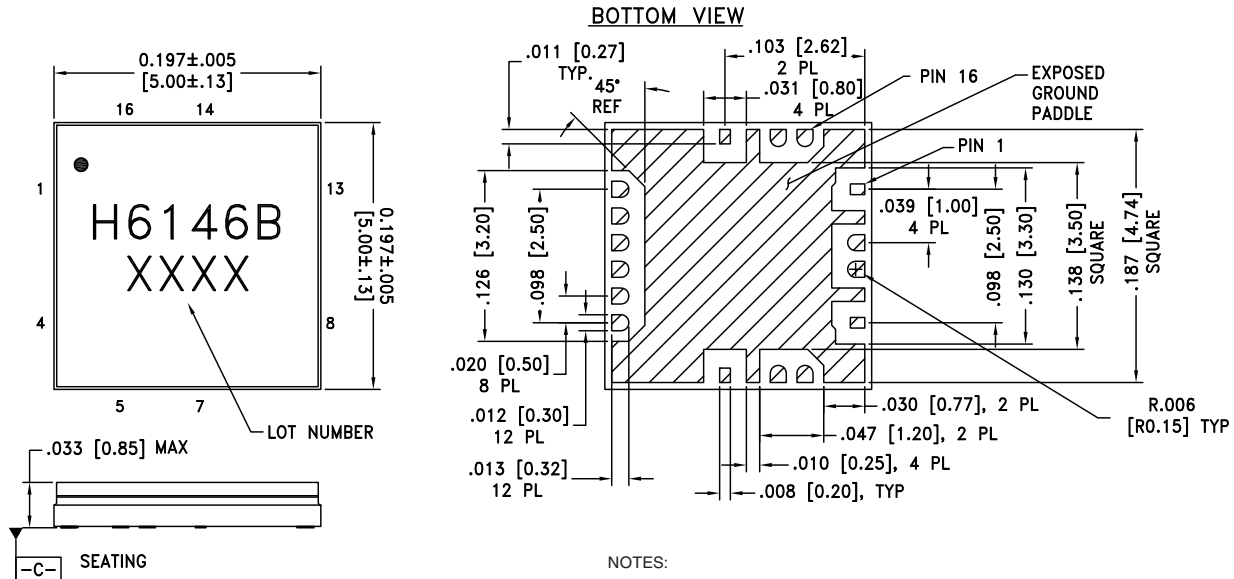
### Absolute Maximum Ratings

IF Input	+20 dBm
LO Input	+10 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85°C) (derate 18.3 mW/°C above 85°C)	1.65 W
Thermal Resistance (channel to ground paddle)	54.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0 Passed 150V



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30 - 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKLE
3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC6146BLC5A	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	6146B XXXX

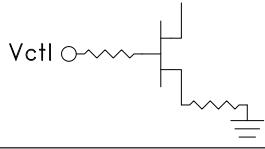
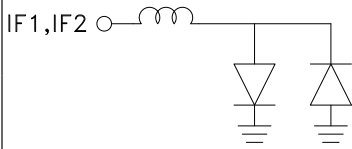
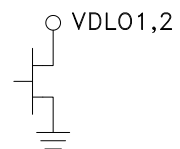

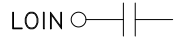
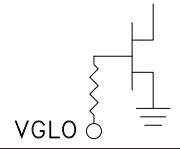
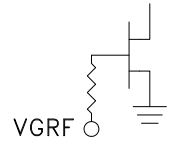
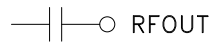
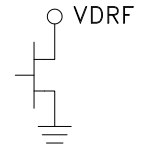
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

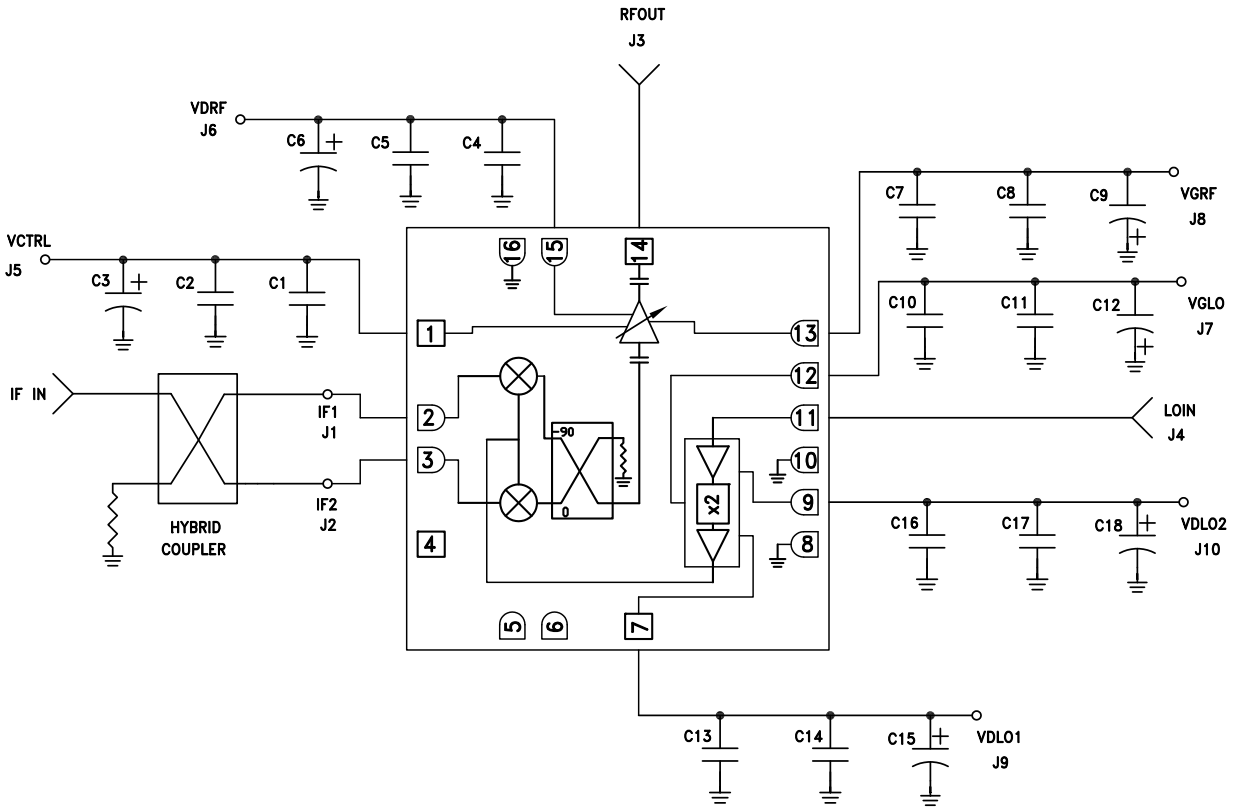


## GaAs MMIC I/Q UPCONVERTER 40 - 44 GHz

### Pin Descriptions

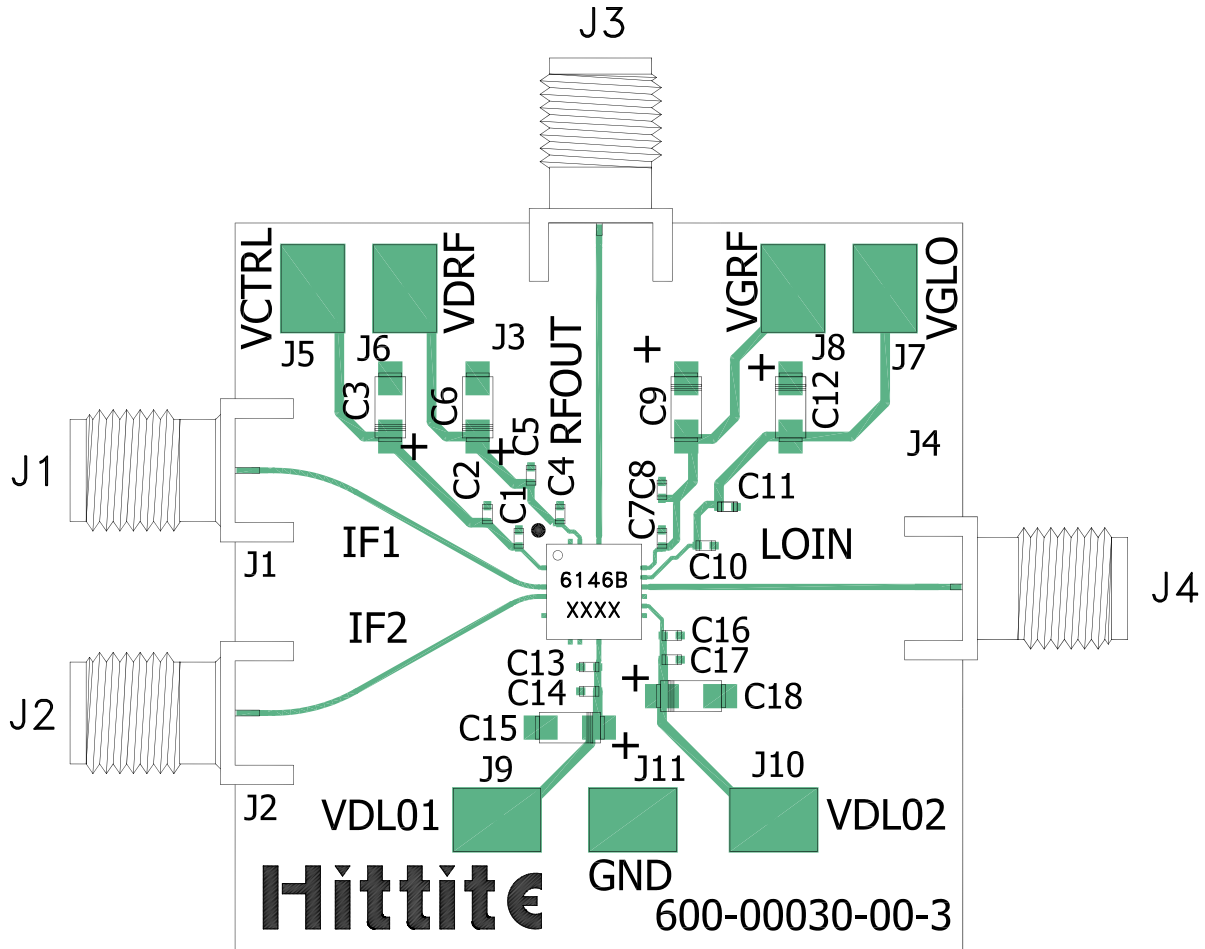
Pin Number	Function	Description	Interface Schematic
1	VCTRL	Vary Vctrl from -2V to 0V to adjust conversion gain. Maximum Gain occurs at -2V. Current draw << 1 mA.	
2	IF1	Pins are DC coupled Must not source or sink more than +/- 3 mA for applications requiring operation to DC.	
3	IF2		
4, 5, 6	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
7	VDLO1	Bias for multiplier input buffer amp. The recommended DC voltage is +3V.	
9	VDLO2	Bias for multiplier input buffer amp. The recommended DC voltage is +3V.	
8, 10, 16	GND	These pins and package bottom must be connected to RF/DC ground.	
11	LOIN	LO input port. The recommended LO power is 0 to 5 dBm.	
12	VGLO	Adjust VGLO for -1V to 0V to set the multiplier quiescent current to 120 mA ( 200 - 230 mA with LO Drive ).	
13	VGRF	Adjust VGRF for -1V to 0V to set the VGA current to 200 mA.	
14	RFOUT	RF output port.	
15	VDRF	Bias voltage for the VGA.	

### Typical Application



C1, C4, C7, C10, C13, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C8, C11, C14, C17	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C9, C12, C15, C18	4.7 μF Capacitor, Case A Pkg.

### Evaluation PCB



### List of Materials for Evaluation PCB Eval01-HMC6146BLC5A [1]

Item	Description
J1, J2	SMA Connector
J3, J4	K-Connector SRI
J5 - J11	DC Pins
C1, C4, C7, C10, C13, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C8, C11, C14, C17	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C9, C12, C15, C18	4.7 uF Capacitor, Case A
U1	HMC6146BLC5A Upconverter
PCB [2]	600-00030-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



## Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

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С нами вы становитесь еще успешнее!

### Наши контакты:

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331